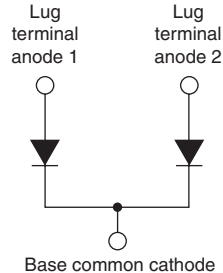


Schottky Rectifier, 200 A



TO-244



FEATURES

- 150 °C T_J operation
- Center tap module
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Lead (Pb)-free ("PbF" suffix)
- Designed and qualified for industrial level


RoHS
COMPLIANT

PRODUCT SUMMARY

$I_{F(AV)}$	200 A
V_R	45 V

DESCRIPTION

The 200CNQ... center tap Schottky rectifier module series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in high current switching power supplies, plating power supplies, UPS systems, converters, freewheeling diodes, welding, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS

SYMBOL	CHARACTERISTICS	VALUES	UNITS
$I_{F(AV)}$	Rectangular waveform	200	A
V_{RRM}		45	V
I_{FSM}	$t_p = 5 \mu s$ sine	26 000	A
V_F	100 Apk, $T_J = 125 \text{ }^\circ\text{C}$ (per leg)	0.52	V
T_J	Range	- 55 to 150	$^\circ\text{C}$

VOLTAGE RATINGS

PARAMETER	SYMBOL	200CNQ045PbF	UNITS
Maximum DC reverse voltage	V_R	45	V
Maximum working peak reverse voltage	V_{RWM}		

ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current See fig. 5	$I_{F(AV)}$	50 % duty cycle at $T_C = 116 \text{ }^\circ\text{C}$, rectangular waveform	100	A
			200	
Maximum peak one cycle non-repetitive surge current per leg See fig. 7	I_{FSM}	5 μs sine or 3 μs rect. pulse	26 000	A
		10 ms sine or 6 ms rect. pulse		
Non-repetitive avalanche energy per leg	E_{AS}	$T_J = 25 \text{ }^\circ\text{C}$, $I_{AS} = 17 \text{ A}$, $L = 1 \text{ mH}$	135	mJ
Repetitive avalanche current per leg	I_{AR}	Current decaying linearly to zero in 1 μs Frequency limited by T_J maximum $V_A = 1.5 \times V_R$ typical	20	A

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop per leg See fig. 1	$V_{FM}^{(1)}$	100 A	$T_J = 25\text{ }^\circ\text{C}$	0.55	V
		200 A		0.73	
		100 A	$T_J = 125\text{ }^\circ\text{C}$	0.52	
		200 A		0.69	
Maximum reverse leakage current per leg See fig. 2	$I_{RM}^{(1)}$	$T_J = 25\text{ }^\circ\text{C}$	$V_R = \text{Rated } V_R$	10	mA
		$T_J = 125\text{ }^\circ\text{C}$		800	
Threshold voltage	$V_{F(TO)}$	$T_J = T_J \text{ maximum}$		0.27	V
Forward slope resistance	r_t			2.0	$\text{m}\Omega$
Maximum junction capacitance per leg	C_T	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz) $25\text{ }^\circ\text{C}$		5200	pF
Typical series inductance per leg	L_S	From top of terminal hole to mounting plane		7.0	nH
Maximum voltage rate of change	dV/dt	Rated V_R		10 000	$\text{V}/\mu\text{s}$

Note

(1) Pulse width < 300 μs , duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T_J, T_{Stg}	- 55	-	150	$^\circ\text{C}$
Thermal resistance, junction to case — per leg per module	R_{thJC}	-	-	0.38	$^\circ\text{C}/\text{W}$
		-	-	0.19	
Thermal resistance, case to heatsink	R_{thCS}	-	0.10	-	
Weight		-	68	-	g
			2.4		oz.
Mounting torque		35.4 (4)	-	53.1 (6)	lbf · in (N · m)
Mounting torque center hole		30 (3.4)	-	40 (4.6)	
Terminal torque		30 (3.4)	-	44.2 (5)	
Vertical pull		-	-	80	lbf · in
2" lever pull		-	-	35	

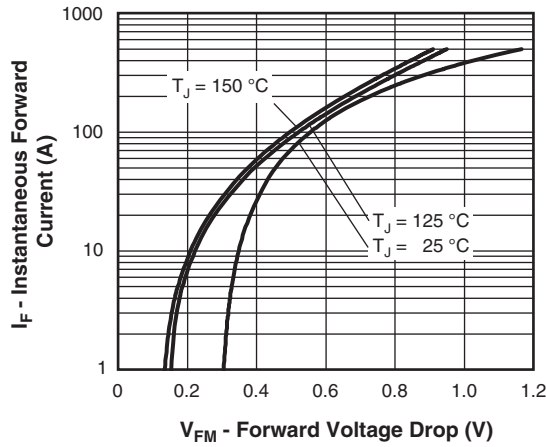


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

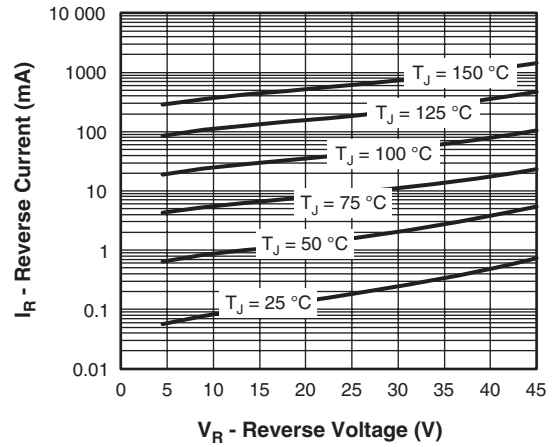


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

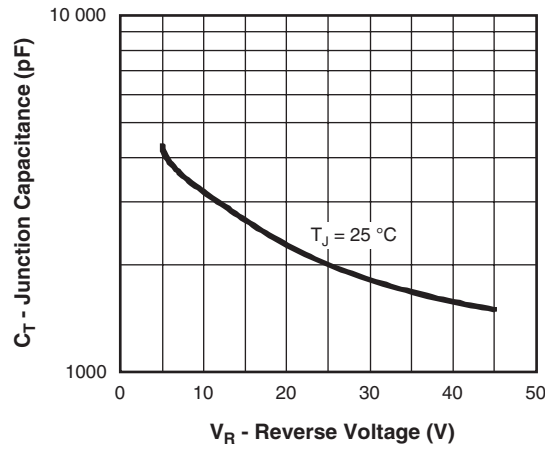


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

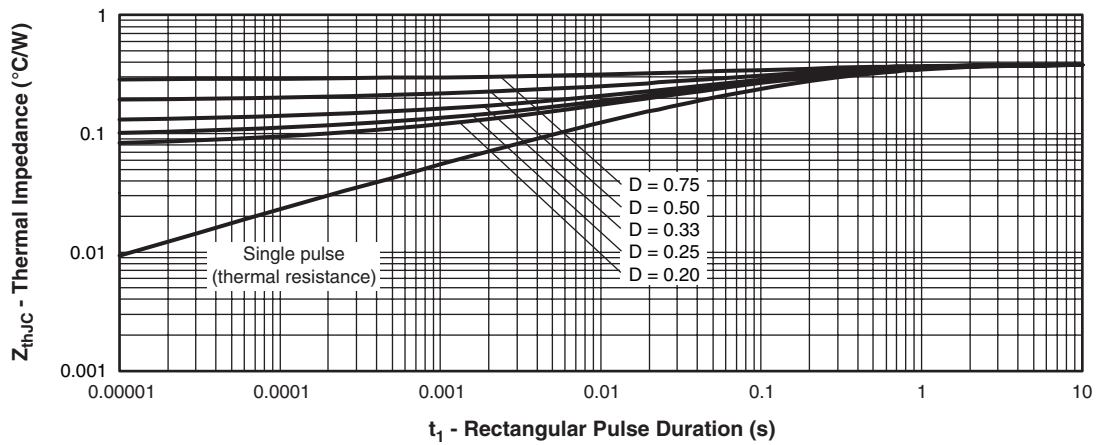


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

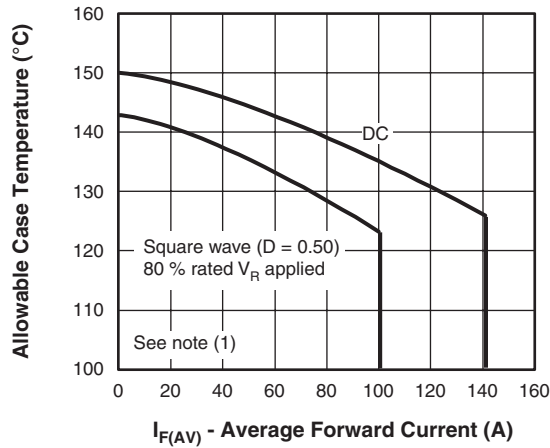


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

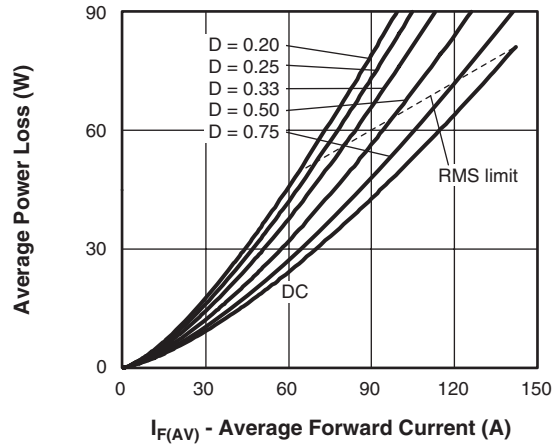


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

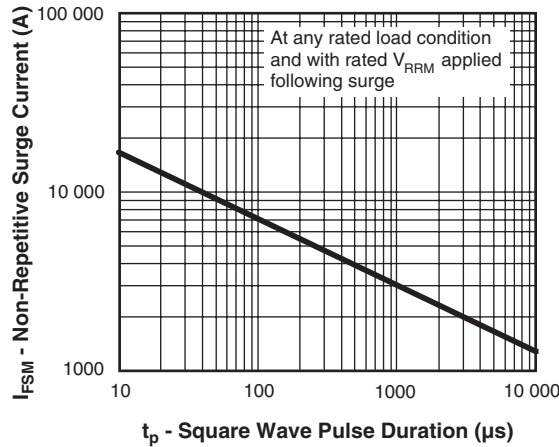


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)



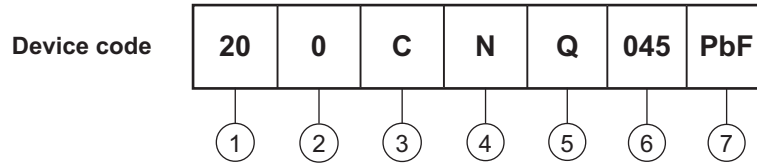
Fig. 8 - Unclamped Inductive Test Circuit

Note

- (1) Formula used: $T_C = T_J - (P_d + P_{d_{REV}}) \times R_{thJC}$;
- P_d = Forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6);
- $P_{d_{REV}}$ = Inverse power loss = $V_{R1} \times I_R (1 - D)$; I_R at $V_{R1} = 80\%$ rated V_R



ORDERING INFORMATION TABLE



- 1** - Average current rating (x 10)
- 2** - Product silicon identification
- 3** - C = Circuit configuration
- 4** - N = Not isolated
- 5** - Q = Schottky rectifier diode
- 6** - Voltage rating (045 = 45 V)
- 7** - Lead (Pb)-free

LINKS TO RELATED DOCUMENTS	
Dimensions	http://www.vishay.com/doc?95021



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